## 1. General description

The 74LVC1G384 provides one single pole, single throw analog switch function. It has two input/output terminals (Y and Z) and an active LOW enable input pin ( $\overline{E}$ ). When pin  $\overline{E}$  is HIGH, the analog switch is turned off.

Schmitt trigger action at the enable input makes the circuit tolerant of slower input rise and fall times across the entire  $V_{CC}$  range from 1.65 V to 5.5 V.

## 2. Features and benefits

- Wide supply voltage range from 1.65 V to 5.5 V
- Very low ON resistance:
  - 7.5  $\Omega$  (typical) at V<sub>CC</sub> = 2.7 V
  - 6.5 Ω (typical) at V<sub>CC</sub> = 3.3 V
  - 6  $\Omega$  (typical) at V<sub>CC</sub> = 5 V
- ESD protection:
  - ◆ HBM JESD22-A114F exceeds 2000 V
  - MM JESD22-A115-A exceeds 200 V
- Switch current capability of 32 mA
- High noise immunity
- CMOS low power consumption
- TTL interface compatibility at 3.3 V
- Latch-up performance meets requirements of JESD 78 Class I
- Enable input accepts voltages up to 5.5 V
- Inputs accept voltages up to 5 V
- Multiple package options
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C

## 3. Ordering information

#### Table 1. Ordering information

Type number	Package							
	Temperature range Name Description							
74LVC1G384GW	–40 °C to +125 °C	TSSOP5	plastic thin shrink small outline package; 5 leads; body width 1.25 mm	SOT353-1				
74LVC1G384GV	–40 °C to +125 °C	SC-74A	plastic surface-mounted package; 5 leads	SOT753				
74LVC1G384GM	–40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 $\times$ 1.45 $\times$ 0.5 mm	SOT886				



### **NXP Semiconductors**

# 74LVC1G384

**Bilateral switch** 

#### Table 1. Ordering information ...continued

Type number	Package							
	Temperature range Name Description							
74LVC1G384GF	–40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 $\times$ 1 $\times$ 0.5 mm	SOT891				
74LVC1G384GN	–40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body $0.9 \times 1.0 \times 0.35$ mm	SOT1115				
74LVC1G384GS	–40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body $1.0 \times 1.0 \times 0.35$ mm	SOT1202				

## 4. Marking

Table 2. Marking	
Type number	Marking code <sup>[1]</sup>
74LVC1G384GW	YL
74LVC1G384GV	YL
74LVC1G384GM	YL
74LVC1G384GF	YL
74LVC1G384GN	YL
74LVC1G384GS	YL

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

# 5. Functional diagram

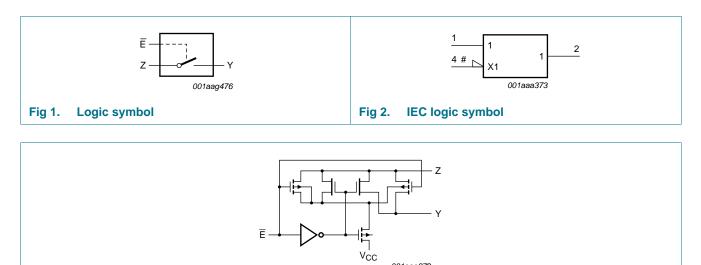


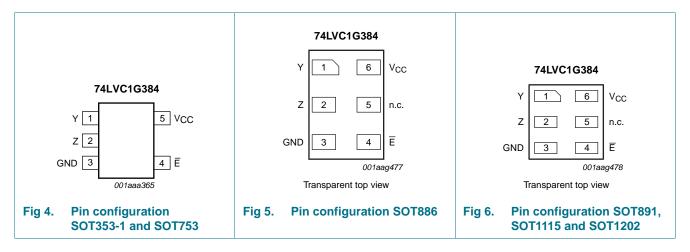
Fig 3. Logic diagram

74LVC1G384 Product data sheet

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## 6. Pinning information

## 6.1 Pinning



## 6.2 Pin description

Symbol	Pin		Description	
	SOT353-1, SOT753	SOT886, SOT891, SOT1115 and SOT1202	-	
Y	1	1	independent input or output	
Z	2	2	independent output or input	
GND	3	3	ground (0 V)	
E	4	4	enable input (active LOW)	
n.c.	-	5	not connected	
V <sub>CC</sub>	5	6	supply voltage	

## 7. Functional description

	Function table <sup>[1]</sup>	
Input E	Swit	ch in the second s
L	ON-s	tate
Н	OFF	state

[1] H = HIGH voltage level; L = LOW voltage level.

## 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		-0.5	+6.5	V
VI	input voltage		<u>[1]</u> –0.5	+6.5	V
I <sub>IK</sub>	input clamping current	$V_{\rm I}$ < –0.5 V or $V_{\rm I}$ > $V_{\rm CC}$ + 0.5 V	-50	-	mA
I <sub>SK</sub>	switch clamping current	$V_{\rm I}$ < –0.5 V or $V_{\rm I}$ > $V_{\rm CC}$ + 0.5 V	-	±50	mA
V <sub>SW</sub>	switch voltage	enable and disable mode	<u>[2]</u> –0.5	$V_{CC} + 0.5$	V
I <sub>SW</sub>	switch current	$V_{SW}$ > –0.5 V or $V_{SW}$ < $V_{CC}$ + 0.5 V	-	±50	mA
I <sub>CC</sub>	supply current		-	100	mA
I <sub>GND</sub>	ground current		-100	-	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	$T_{amb} = -40 \circ C$ to +125 $\circ C$	<u>[3]</u>	250	mW

[1] The minimum input voltage rating may be exceeded if the input current rating is observed.

[2] The minimum and maximum switch voltage ratings may be exceeded if the switch clamping current rating is observed.

[3] For TSSOP5 and SC-74A packages: above 87.5 °C the value of P<sub>tot</sub> derates linearly with 4.0 mW/K. For XSON6 package: above 118 °C the value of P<sub>tot</sub> derates linearly with 7.8 mW/K.

## 9. Recommended operating conditions

#### Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>CC</sub>	supply voltage		1.65	-	5.5	V
VI	input voltage		0	-	5.5	V
V <sub>SW</sub>	switch voltage		<u>[1]</u> 0	-	V <sub>CC</sub>	V
T <sub>amb</sub>	ambient temperature		-40	-	+125	°C
$\Delta t / \Delta V$	input transition rise and fall rate	$V_{CC}$ = 1.65 V to 2.7 V	-	-	20	ns/V
		$V_{CC}$ = 2.7 V to 5.5 V	-	-	10	ns/V

[1] To avoid sinking GND current from terminal Z when switch current flows in terminal Y, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal Z, no GND current will flow from terminal Y. In this case, there is no limit for the voltage drop across the switch.



**Bilateral switch** 

# **10. Static characteristics**

#### Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		-40 °	°C to +8	5 °C	–40 °C to	Unit	
				Min	Typ[1]	Max	Min	Max	-
V <sub>IH</sub>	HIGH-level	$V_{CC} = 1.65 \text{ V} \text{ to } 1.95 \text{ V}$		$0.65V_{CC}$	-	-	0.65 V <sub>CC</sub>	-	V
	input voltage	$V_{CC}$ = 2.3 V to 2.7 V		1.7	-	-	1.7	-	V
		$V_{CC}$ = 2.7 V to 3.6 V		2.0	-	-	2.0	-	V
		$V_{CC}$ = 4.5 V to 5.5 V		$0.7V_{CC}$	-	-	$0.7V_{CC}$	-	V
V <sub>IL</sub>	LOW-level	$V_{CC}$ = 1.65 V to 1.95 V		-	-	$0.35V_{CC}$	-	$0.35V_{CC}$	V
	input voltage	$V_{CC}$ = 2.3 V to 2.7 V		-	-	0.7	-	0.7	V
		$V_{CC}$ = 2.7 V to 3.6 V		-	-	0.8	-	0.8	V
		$V_{CC}$ = 4.5 V to 5.5 V		-	-	$0.3V_{CC}$	-	$0.3V_{CC}$	V
I <sub>I</sub>	input leakage current	pin $\overline{E}$ ; V <sub>I</sub> = 5.5 V or GND; V <sub>CC</sub> = 0 V to 5.5 V	[2]	-	±0.1	±5	-	100	μA
I <sub>S(OFF)</sub>	OFF-state leakage current	$V_{CC}$ = 5.5 V; see <u>Figure 7</u>	[2]	-	±0.1	±5	-	200	μΑ
I <sub>S(ON)</sub>	ON-state leakage current	V <sub>CC</sub> = 5.5 V; see <u>Figure 8</u>	[2]	-	±0.1	±5	-	200	μΑ
I <sub>CC</sub>	supply current	$V_{\rm I}$ = 5.5 V or GND; $V_{\rm SW}$ = GND or $V_{\rm CC}; V_{\rm CC}$ = 1.65 V to 5.5 V	[2]	-	0.1	10	-	200	μΑ
$\Delta I_{CC}$	additional supply current	pin $\overline{E}$ ; V <sub>I</sub> = V <sub>CC</sub> - 0.6 V; V <sub>SW</sub> = GND or V <sub>CC</sub> ; V <sub>CC</sub> = 5.5 V	[2]	-	5	500	-	5000	μΑ
CI	input capacitance			-	2.0	-	-	-	pF
$C_{S(OFF)}$	OFF-state capacitance			-	5.0	-	-	-	pF
C <sub>S(ON)</sub>	ON-state capacitance			-	9.5	-	-	-	pF

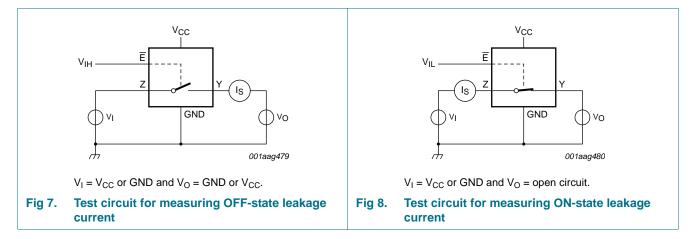
[1] All typical values are measured at  $T_{amb} = 25 \text{ °C}$ .

[2] These typical values are measured at V<sub>CC</sub> = 3.3 V.

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**Bilateral switch** 

### **10.1 Test circuits**



### 10.2 ON resistance

#### Table 8.ON resistance

At recommended operating conditions; voltages are referenced to GND (ground 0 V); for graphs see Figure 10 to Figure 15.

Symbol	Parameter	Conditions	-40	°C to +8	S5 ℃	–40 °C to +125 °C		Unit
			Min	Typ <mark>[1]</mark>	Max	Min	Max	
R <sub>ON(peak)</sub>	ON resistance (peak)	$V_I = GND$ to $V_{CC}$ ; see <u>Figure 9</u>						
		I <sub>SW</sub> = 4 mA; V <sub>CC</sub> = 1.65 V to 1.95 V	-	34.0	130	-	195	Ω
		$I_{SW}$ = 8 mA; $V_{CC}$ = 2.3 V to 2.7 V	-	12.0	30	-	45	Ω
		$I_{SW}$ = 12 mA; $V_{CC}$ = 2.7 V	-	10.4	25	-	38	Ω
		$I_{SW}$ = 24 mA; $V_{CC}$ = 3 V to 3.6 V	-	7.8	20	-	30	Ω
		$I_{SW}$ = 32 mA; $V_{CC}$ = 4.5 V to 5.5 V	-	6.2	15	-	23	Ω
R <sub>ON(rail)</sub>	ON resistance (rail)	V <sub>I</sub> = GND; see <u>Figure 9</u>						
	I <sub>SW</sub> = 4 mA; V <sub>CC</sub> = 1.65 V to 1.95 V	-	8.2	18	-	27	Ω	
		$I_{SW}$ = 8 mA; $V_{CC}$ = 2.3 V to 2.7 V	-	7.1	16	-	24	Ω
		$I_{SW}$ = 12 mA; $V_{CC}$ = 2.7 V	-	6.9	14	-	21	Ω
		$I_{SW}$ = 24 mA; $V_{CC}$ = 3 V to 3.6 V	-	6.5	12	-	18	Ω
		$I_{SW}$ = 32 mA; $V_{CC}$ = 4.5 V to 5.5 V	-	5.8	10	-	15	Ω
		$V_{I} = V_{CC}$ ; see Figure 9				-		
		I <sub>SW</sub> = 4 mA; V <sub>CC</sub> = 1.65 V to 1.95 V	-	10.4	30	-	45	Ω
		$I_{SW}$ = 8 mA; $V_{CC}$ = 2.3 V to 2.7 V	-	7.6	20	-	30	Ω
		$I_{SW}$ = 12 mA; $V_{CC}$ = 2.7 V	-	7.0	18	-	27	Ω
		$I_{SW}$ = 24 mA; $V_{CC}$ = 3 V to 3.6 V	-	6.1	15	-	23	Ω
		$I_{SW}$ = 32 mA; $V_{CC}$ = 4.5 V to 5.5 V	-	4.9	10	-	15	Ω

**Bilateral switch** 

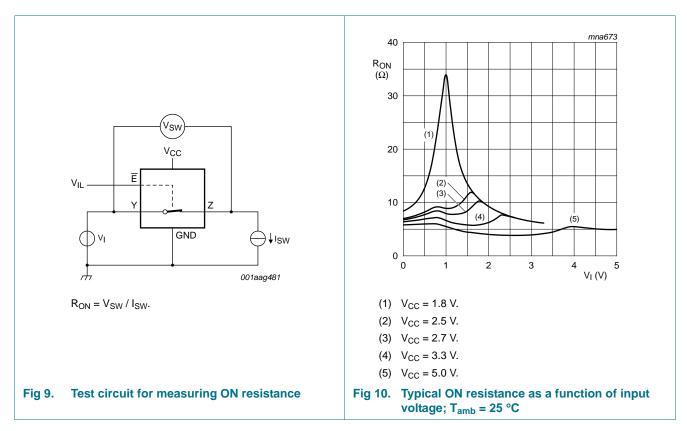
Symbol	Parameter	Conditions	Conditions		–40 °C to +85 °C		–40 °C to	o +125 °C	Unit
				Min	Typ[1]	Max	Min	Max	
R <sub>ON(flat)</sub> ON resistance (flatness)	$V_I = GND$ to $V_{CC}$	[2]							
	I <sub>SW</sub> = 4 mA; V <sub>CC</sub> = 1.65 V to 1.95 V		-	26.0	-	-	-	Ω	
		$I_{SW}$ = 8 mA; $V_{CC}$ = 2.3 V to 2.7 V		-	5.0	-	-	-	Ω
		$I_{SW}$ = 12 mA; $V_{CC}$ = 2.7 V		-	3.5	-	-	-	Ω
		$I_{SW}$ = 24 mA; $V_{CC}$ = 3 V to 3.6 V		-	2.0	-	-	-	Ω
		$I_{SW}$ = 32 mA; $V_{CC}$ = 4.5 V to 5.5 V		-	1.5	-	-	-	Ω

#### Table 8. ON resistance ...continued

At recommended operating conditions; voltages are referenced to GND (ground 0 V); for graphs see Figure 10 to Figure 15.

[1] Typical values are measured at  $T_{amb}$  = 25 °C and nominal V<sub>CC</sub>.

[2] Flatness is defined as the difference between the maximum and minimum value of ON resistance measured at identical V<sub>CC</sub> and temperature.

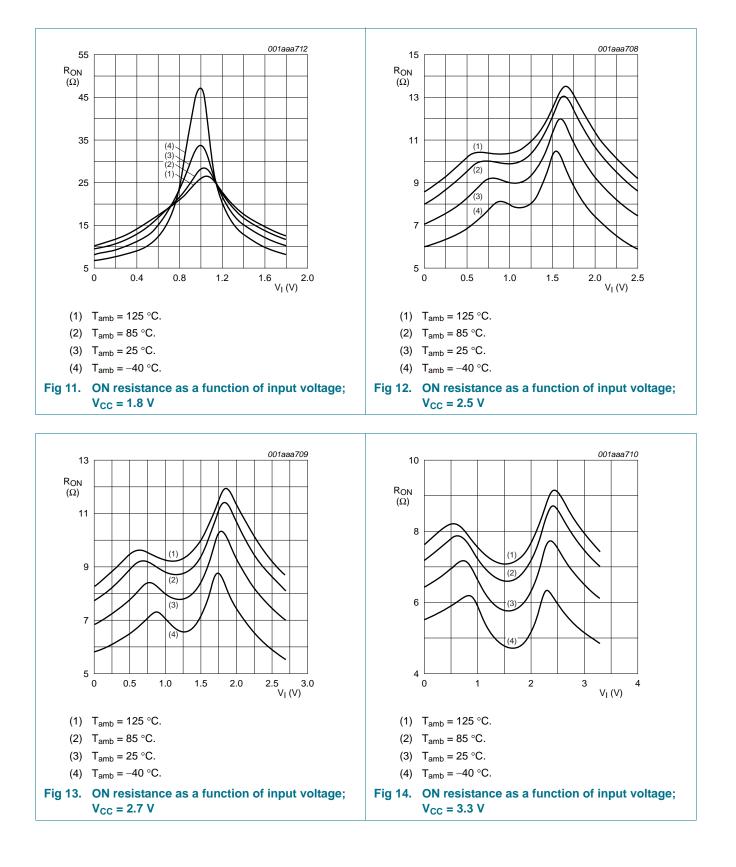


### 10.3 ON resistance test circuit and graphs

### **NXP Semiconductors**

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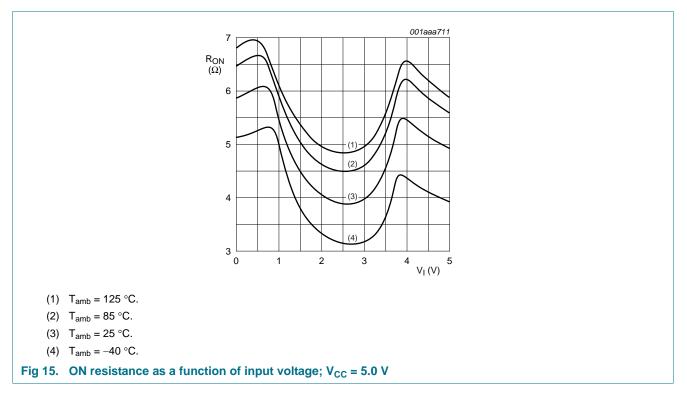
#### **Bilateral switch**



### **NXP Semiconductors**

# 74LVC1G384

#### **Bilateral switch**



## **11. Dynamic characteristics**

#### Table 9. Dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for test circuit see Figure 18.

Symbol	Parameter	Conditions		-40	°C to +8	5 °C	–40 °C to	Unit	
				Min	Typ[1]	Max	Min	Max	
t <sub>pd</sub>	propagation delay	Y to Z or Z to Y; see Figure 16	[2][3]						
		$V_{CC}$ = 1.65 V to 1.95 V		-	0.8	2.0	-	3.0	ns
		$V_{CC}$ = 2.3 V to 2.7 V		-	0.4	1.2	-	2.0	ns
		$V_{CC} = 2.7 V$		-	0.4	1.0	-	1.5	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		-	0.3	0.8	-	1.5	ns
		$V_{CC}$ = 4.5 V to 5.5 V		-	0.2	0.6	-	1.0	ns
t <sub>en</sub>	enable time	$\overline{E}$ to Y or Z; see Figure 17	<u>[4]</u>						
		$V_{CC}$ = 1.65 V to 1.95 V		1.0	10.0	12.0	1.0	15.5	ns
		$V_{CC}$ = 2.3 V to 2.7 V		1.0	5.7	6.5	1.0	8.5	ns
		$V_{CC} = 2.7 V$		1.0	5.4	6.0	1.0	8.0	ns
		$V_{CC}$ = 3.0 V to 3.6 V		1.0	4.8	5.0	1.0	6.5	ns
		$V_{CC}$ = 4.5 V to 5.5 V		1.0	3.3	4.2	1.0	5.5	ns

**Bilateral switch** 

Symbol	Parameter	Conditions		-40	°C to +8	S °C	–40 °C to	o +125 ℃	Unit
				Min	Typ <mark>[1]</mark>	Max	Min	Max	
t <sub>dis</sub>	disable time	E to Y or Z; see Figure 17	<u>[5]</u>		•				
		$V_{CC}$ = 1.65 V to 1.95 V		1.0	7.4	10.0	1.0	13.0	ns
		$V_{CC}$ = 2.3 V to 2.7 V		1.0	4.1	6.9	1.0	9.0	ns
		$V_{CC} = 2.7 V$		1.0	4.9	7.5	1.0	9.5	ns
		$V_{CC}$ = 3.0 V to 3.6 V		1.0	5.4	6.5	1.0	8.5	ns
		$V_{CC}$ = 4.5 V to 5.5 V		1.0	3.6	5.0	1.0	6.5	ns
C <sub>PD</sub>	power dissipation capacitance	$C_L$ = 50 pF; f <sub>i</sub> = 10 MHz; V <sub>I</sub> = GND to V <sub>CC</sub>	<u>[6]</u>						
		$V_{CC} = 2.5 V$		-	13.7	-	-	-	pF
		$V_{CC} = 3.3 V$		-	15.2	-	-	-	pF
		$V_{CC} = 5.0 V$		-	18.3	-	-	-	pF

#### Table 9. Dynamic characteristics ... continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for test circuit see Figure 18.

[1] Typical values are measured at  $T_{amb}$  = 25 °C and nominal V<sub>CC</sub>.

[2]  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .

[3] propagation delay is the calculated RC time constant of the typical ON resistance of the switch and the specified capacitance when driven by an ideal voltage source (zero output impedance).

 $\label{eq:tensor} [4] \quad t_{en} \text{ is the same as } t_{PZH} \text{ and } t_{PZL}.$ 

[5]  $t_{dis}$  is the same as  $t_{PLZ}$  and  $t_{PHZ}$ .

[6]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ).

 $\mathsf{P}_{\mathsf{D}} = \mathsf{C}_{\mathsf{P}\mathsf{D}} \times \mathsf{V}_{\mathsf{C}\mathsf{C}}^2 \times \mathsf{f}_i \times \mathsf{N} + \Sigma\{(\mathsf{C}_{\mathsf{L}} + \mathsf{C}_{\mathsf{S}(\mathsf{ON})}) \times \mathsf{V}_{\mathsf{C}\mathsf{C}}^2 \times \mathsf{f}_o\} \text{ where:}$ 

 $f_i = input frequency in MHz;$ 

 $f_o = output frequency in MHz;$ 

 $C_L$  = output load capacitance in pF;

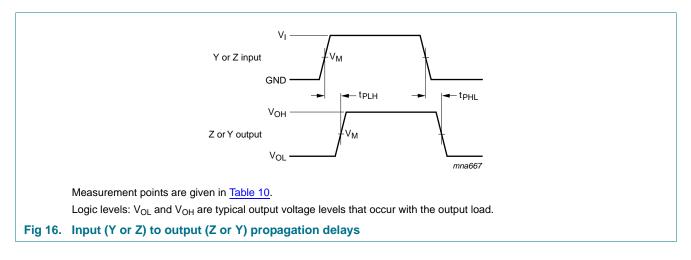
C<sub>S(ON)</sub> = maximum ON-state switch capacitance in pF;

V<sub>CC</sub> = supply voltage in V;

N = number of inputs switching;

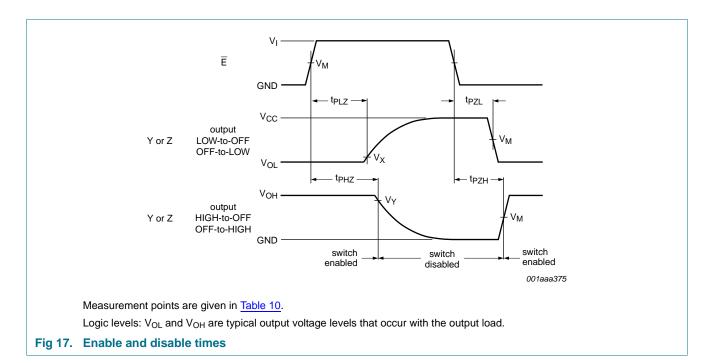
 $\Sigma$ {(C<sub>L</sub> + C<sub>S(ON)</sub>) × V<sub>CC</sub><sup>2</sup> × f<sub>o</sub>} = sum of the outputs.

### 11.1 Waveforms and test circuit



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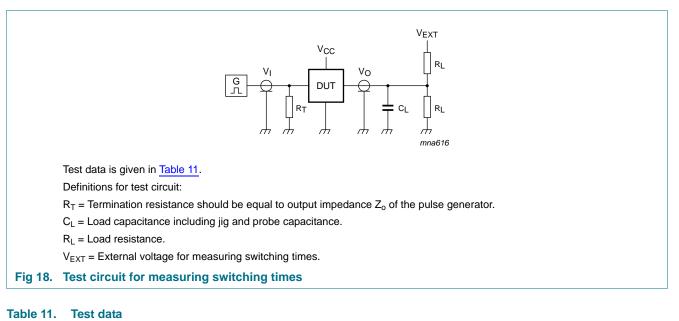
#### **Bilateral switch**



#### Table 10. Measurement points

Supply voltage	Input	Output			
V <sub>cc</sub>	V <sub>M</sub>	V <sub>M</sub>	V <sub>X</sub>	VY	
1.65 V to 1.95 V	0.5V <sub>CC</sub>	$0.5V_{CC}$	V <sub>OL</sub> + 0.15 V	V <sub>OH</sub> – 0.15 V	
2.3 V to 2.7 V	0.5V <sub>CC</sub>	$0.5V_{CC}$	V <sub>OL</sub> + 0.15 V	V <sub>OH</sub> – 0.15 V	
2.7 V	1.5 V	1.5 V	V <sub>OL</sub> + 0.3 V	V <sub>OH</sub> – 0.3 V	
3.0 V to 3.6 V	1.5 V	1.5 V	V <sub>OL</sub> + 0.3 V	V <sub>OH</sub> – 0.3 V	
4.5 V to 5.5 V	0.5V <sub>CC</sub>	$0.5V_{CC}$	V <sub>OL</sub> + 0.3 V	V <sub>OH</sub> – 0.3 V	

#### **Bilateral switch**



Supply voltage Input		Load	Load		V <sub>EXT</sub>		
V <sub>cc</sub>	VI	t <sub>r</sub> , t <sub>f</sub>	CL	RL	t <sub>PLH</sub> , t <sub>PHL</sub>	t <sub>PZH</sub> , t <sub>PHZ</sub>	t <sub>PZL</sub> , t <sub>PLZ</sub>
1.65 V to 1.95 V	V <sub>CC</sub>	$\leq$ 2.0 ns	30 pF	1 kΩ	open	GND	2V <sub>CC</sub>
2.3 V to 2.7 V	V <sub>CC</sub>	$\leq$ 2.0 ns	30 pF	500 Ω	open	GND	$2V_{CC}$
2.7 V	2.7 V	$\leq$ 2.5 ns	50 pF	500 Ω	open	GND	6 V
3.0 V to 3.6 V	2.7 V	$\leq$ 2.5 ns	50 pF	500 Ω	open	GND	6 V
4.5 V to 5.5 V	V <sub>CC</sub>	$\leq$ 2.5 ns	50 pF	500 Ω	open	GND	$2V_{CC}$

### 11.2 Additional dynamic characteristics

#### Table 12. Additional dynamic characteristics

At recommended operating conditions; typical values measured at  $T_{amb} = 25$  °C.

		and				
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
THD	THD total harmonic distortion	R <sub>L</sub> = 10 kΩ; C <sub>L</sub> = 50 pF; f <sub>i</sub> = 1 kHz; see Figure 19				
		V <sub>CC</sub> = 1.65 V	-	0.032	-	%
		$V_{CC} = 2.3 V$	-	0.008	-	%
	$V_{CC} = 3.0 V$	-	0.006	-	%	
		$V_{CC} = 4.5 V$	-	0.001	-	%
		$R_L = 10 \text{ k}\Omega; C_L = 50 \text{ pF}; f_i = 10 \text{ kHz};$ see Figure 19				
		V <sub>CC</sub> = 1.65 V	-	0.068	-	%
		$V_{CC} = 2.3 V$	-	0.009	-	%
	$V_{CC} = 3.0 V$	-	0.008	-	%	
		$V_{CC} = 4.5 V$	-	0.006	-	%

**Bilateral switch** 

#### Table 12. Additional dynamic characteristics ...continued

At recommended operating conditions; typical values measured at  $T_{amb} = 25$  °C.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
f <sub>(-3dB)</sub>	-3 dB frequency response	$R_L = 600 \Omega; C_L = 50 pF;$ see <u>Figure 20</u>				
		V <sub>CC</sub> = 1.65 V	-	135	-	MHz
		$V_{CC} = 2.3 V$	-	145	-	MHz
		$V_{CC} = 3.0 V$	-	150	-	MHz
		$V_{CC} = 4.5 V$	-	155	-	MHz
		$R_L = 50 \Omega; C_L = 5 pF; see Figure 20$				
		V <sub>CC</sub> = 1.65 V	-	> 500	-	MHz
		$V_{CC} = 2.3 V$	-	> 500	-	MHz
		$V_{CC} = 3.0 V$	-	> 500	-	MHz
		$V_{CC} = 4.5 V$	-	> 500	-	MHz
		$R_L = 50 \Omega$ ; $C_L = 10 \text{ pF}$ ; see Figure 20				
		V <sub>CC</sub> = 1.65 V	-	200	-	MHz
		$V_{CC} = 2.3 V$	-	350	-	MHz
		$V_{CC} = 3.0 V$	-	410	-	MHz
		$V_{CC} = 4.5 V$	-	440	-	MHz
α <sub>iso</sub>	isolation (OFF-state)	$R_L = 600 \Omega$ ; $C_L = 50 pF$ ; $f_i = 1 MHz$ ; see <u>Figure 21</u>				
		V <sub>CC</sub> = 1.65 V	-	-46	-	dB
		$V_{CC} = 2.3 V$	-	-46	-	dB
		$V_{CC} = 3.0 V$	-	-46	-	dB
		$V_{CC} = 4.5 V$	-	-46	-	dB
		$R_L = 50 \Omega$ ; $C_L = 5 pF$ ; $f_i = 1 MHz$ ; see <u>Figure 21</u>				
		V <sub>CC</sub> = 1.65 V	-	-37	-	dB
		$V_{CC} = 2.3 V$	-	-37	-	dB
		$V_{CC} = 3.0 V$	-	-37	-	dB
		$V_{CC} = 4.5 V$	-	-37	-	dB
/ <sub>ct</sub>	crosstalk voltage	between digital input and switch;				
		$ \begin{array}{l} R_{L} = 600 \; \Omega; \; C_{L} = 50 \; pF; \; f_{i} = 1 \; MHz; \\ t_{r} = t_{f} = 2 \; ns; \; see \; \underline{Figure \; 22} \end{array} $				
		V <sub>CC</sub> = 1.65 V	-	69	-	mV
		$V_{CC} = 2.3 V$	-	87	-	mV
		$V_{CC} = 3.0 V$	-	156	-	mV
		$V_{CC} = 4.5 V$	-	302	-	mV

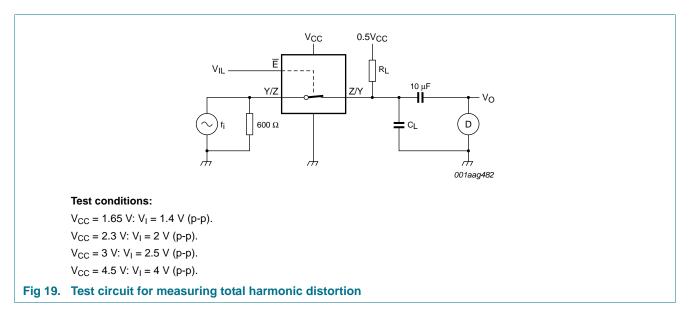
**Bilateral switch** 

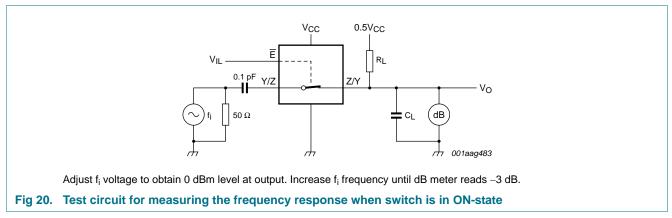
#### Table 12. Additional dynamic characteristics ...continued

At recommended operating conditions; typical values measured at  $T_{amb} = 25$  °C.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Q <sub>inj</sub> charge injection	$C_L = 0.1 \text{ nF}; V_{gen} = 0 \text{ V}; R_{gen} = 0 \Omega;$ $f_i = 1 \text{ MHz}; R_L = 1 \text{ M}\Omega; \text{ see}$ <u>Section 11</u>					
	$V_{CC} = 1.8 V$	-	3.3	-	рС	
	$V_{CC} = 2.5 V$	-	4.1	-	рС	
	$V_{CC} = 3.3 V$	-	5.0	-	рС	
	$V_{CC} = 4.5 V$	-	6.4	-	рС	
		V <sub>CC</sub> = 5.5 V	-	7.5	-	рС

## 11.3 Test circuits

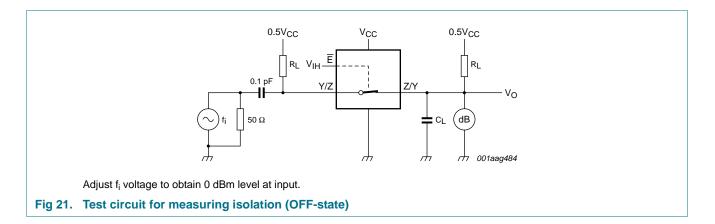


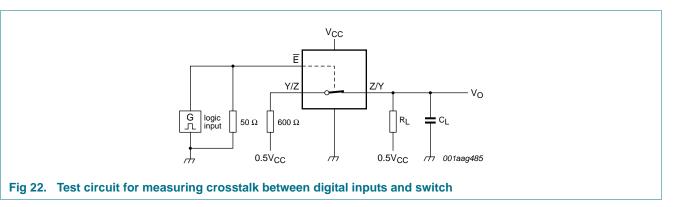


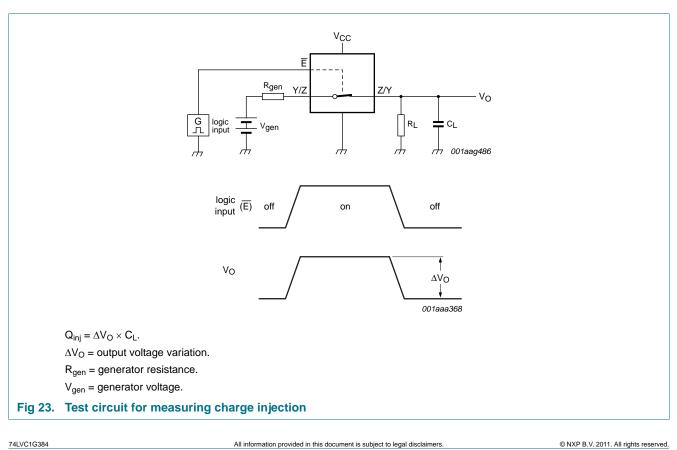
### **NXP Semiconductors**

# 74LVC1G384

#### **Bilateral switch**

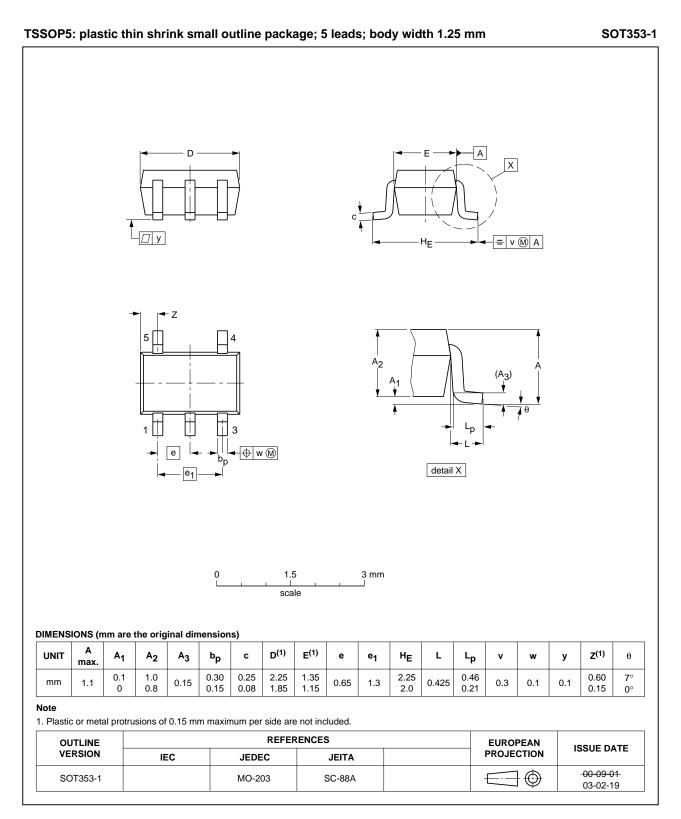






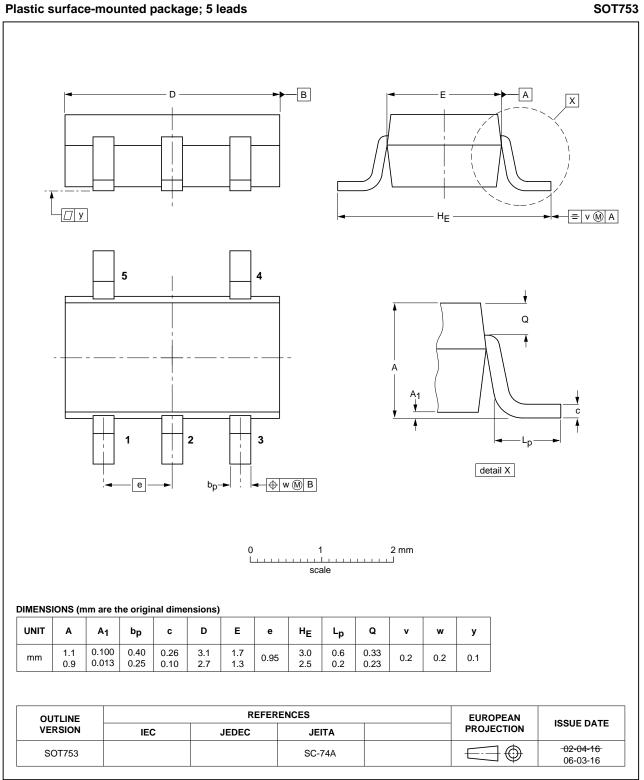
**Bilateral switch** 

## 12. Package outline



#### Fig 24. Package outline SOT353-1 (TSSOP5)

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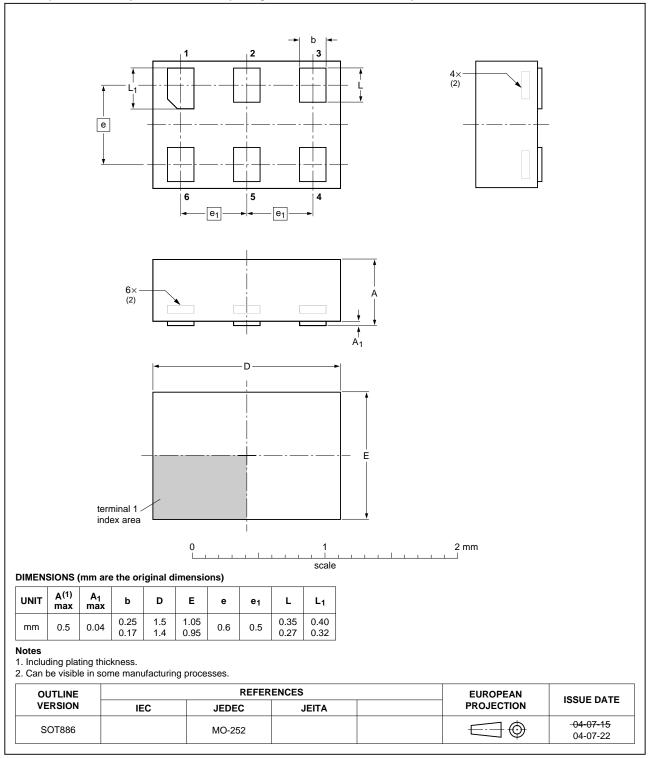


#### Plastic surface-mounted package; 5 leads

Fig 25. Package outline SOT753 (SC-74A)

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SOT886

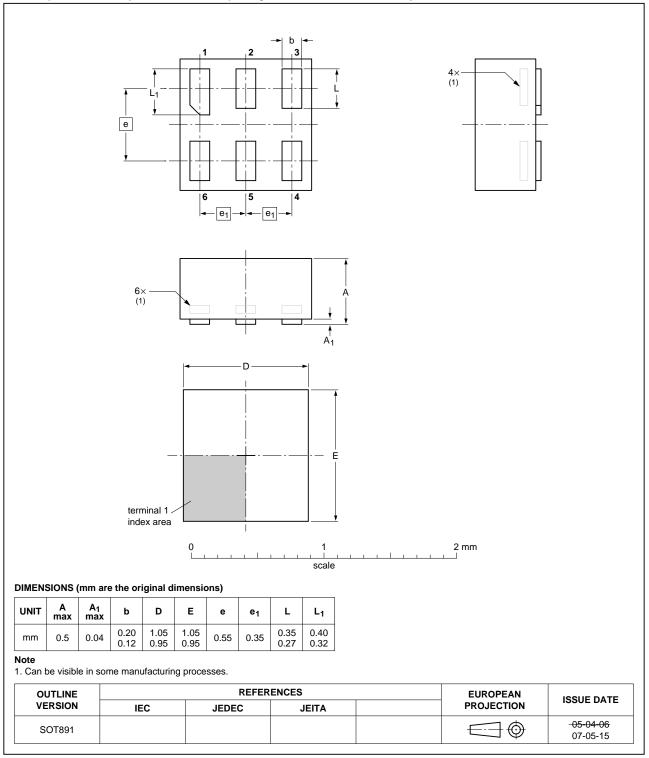


## XSON6: plastic extremely thin small outline package; no leads; 6 terminals; body 1 x 1.45 x 0.5 mm

Fig 26. Package outline SOT886 (XSON6)

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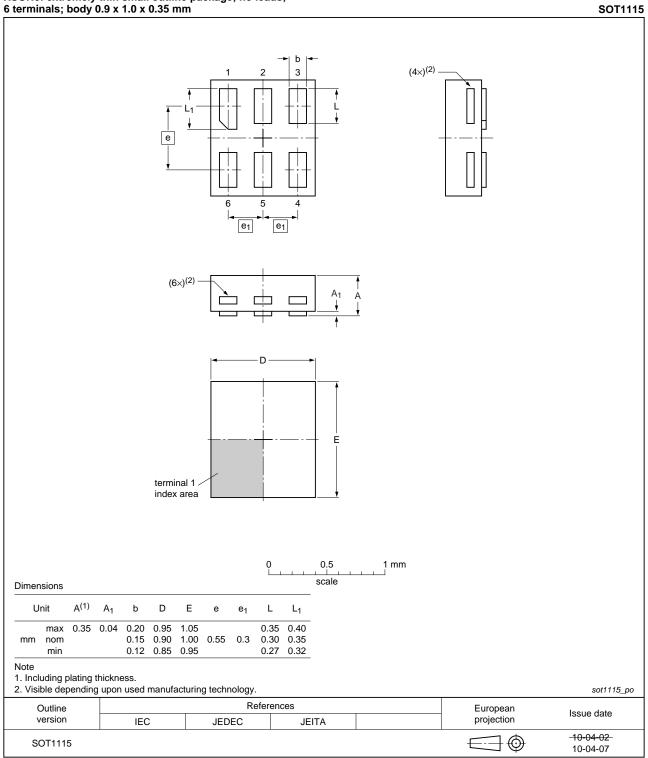
SOT891



XSON6: plastic extremely thin small outline package; no leads; 6 terminals; body 1 x 1 x 0.5 mm

#### Fig 27. Package outline SOT891 (XSON6)

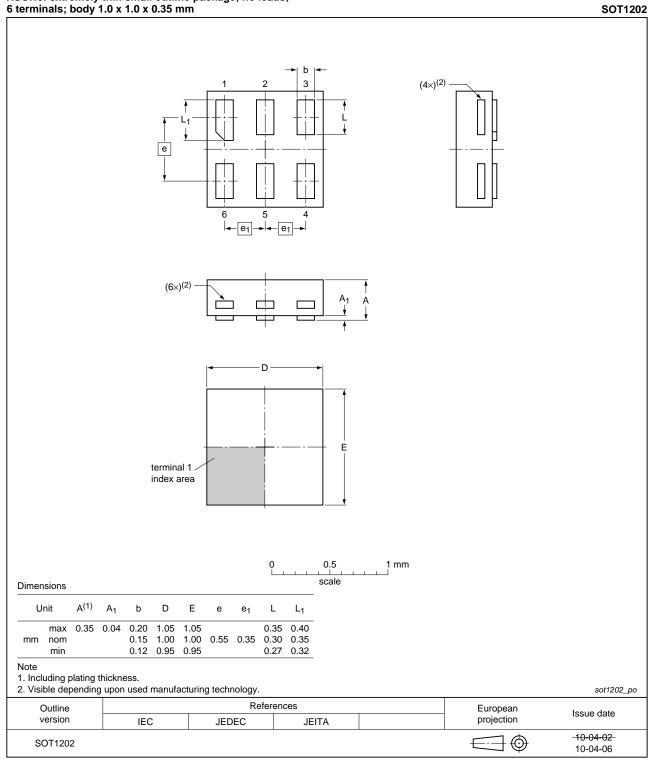
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# XSON6: extremely thin small outline package; no leads; 6 terminals; body 0.9 x 1.0 x 0.35 mm

Fig 28. Package outline SOT1115 (XSON6)

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# XSON6: extremely thin small outline package; no leads; 6 terminals; body 1.0 x 1.0 x 0.35 mm

Fig 29. Package outline SOT1202 (XSON6)

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# 13. Abbreviations

Abbreviations
Description
Complementary Metal Oxide Semiconductor
Device Under Test
ElectroStatic Discharge
Human Body Model
Machine Model
Transistor-Transistor Logic

# 14. Revision history

Table 14. Revision	history			
Document ID	Release date	Data sheet status	Change notice	Supersedes
74LVC1G384 v.4	20111206	Product data sheet	-	74LVC1G384 v.3
Modifications:	<ul> <li>Legal pages</li> </ul>	s updated.		
74LVC1G384 v.3	20101103	Product data sheet	-	74LVC1G384 v.2
74LVC1G384 v.2	20070829	Product data sheet	-	74LVC1G384 v.1
74LVC1G384 v.1	20040226	Product data	-	-

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### 15.1 Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <a href="http://www.nxp.com">http://www.nxp.com</a>.

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#### **Bilateral switch**

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